# NSN 5962-01-210-1193

Memory Microcircuit - Page 1 of 1

AeroBase Group

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# **Body Length:**

Between 0.890 inches and 0.930 inches

# **Body Width:**

Between 0.280 inches and 0.310 inches

# **Body Height:**

Between 0.080 inches and 0.120 inches

## **Operating Tempurature Range:**

-55.0 to 125.0 degrees celsius

## Storage Tempurature Range:

-65.0 to 150.0 degrees celsius

#### **End Application:**

5805-01-032-1694 switchboard, tel

## Features Provided:

Programmable and hermetically sealed and monolithic and schottky

#### **Inclosure Material:**

# Ceramic and glass

Inclosure Configuration:

Dual-in-line

## **Output Logic Form:**

Transistor-transistor logic

## Input Circuit Pattern:

12 input

## **Terminal Surface Treatment:**

Solder

## Voltage Rating And Type Per Characteristic:

7.0 volts power source

## **Time Rating Per Chacteristic:**

125.00 nanoseconds propagation delay time, low to high level output and 125.00 nanoseconds propagation delay time, high to low level output

## Memory Device Type:

Rom

## Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

## Terminal Type And Quantity:

18 printed circuit

#### Shelf Life:

N/a

## Unit Of Measure:

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## Demilitarization:

Yes - demil/mli

#### Fiig:

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